# **Features**

- **Supply Voltage up to 40V**
- Operating Voltage V<sub>S</sub> = 5V to 18V
- **Typically 10 µA Supply Current During Sleep Mode**
- **Typically 40 µA Supply Current in Silent Mode**
- **Linear Low-drop Voltage Regulator:**
	- $-$  Normal Mode:  $V_{CC} = 5V \pm 2\%/50 \, \text{mA}$
	- $-$  Silent Mode:  $V_{CC}$  = 5V ±7%/50 mA
	- **Sleep Mode: V<sub>CC</sub>** is Switched Off
- **V<sub>CC</sub>** Undervoltage Detection with Reset Output NRES (10 ms Reset Time)
- **Voltage Regulator is Short-circuit and Over-temperature Protected**
- **LIN Physical Layer According to LIN Specification Revision 2.0**
- **Wake-up Capability via LIN Bus (90 µs Dominant)**
- **TXD Time-out Timer (9 ms)**
- **60V Load-dump Protection at LIN Pin**
- **Bus Pin is Overtemperature and Short-circuit Protected versus GND and Battery**
- **High EMC Level**
- **5V CMOS-compatible I/O Pins to MCU**
- **ESD HBM 6 kV at Pins LIN and VS**
- **Interference and Damage Protection According to ISO/CD7637**
- **Package: SO8**

# **1. Description**

ATA6620N is a fully integrated LIN transceiver, designed according to the LIN specification 2.0, with a low-drop voltage regulator (5V/50 mA). The combination of voltage regulator and bus transceiver makes it possible to develop simple, but powerful, slave nodes in LIN Bus systems. ATA6620N is designed to handle the low-speed data communication in vehicles (for example, in convenience electronics). Improved slope control at the LIN driver ensures secure data communication up to 20 kBaud with an RC oscillator for the protocol handling. The bus output is designed to withstand high voltage. Sleep mode (voltage regulator switched off) and Silent mode (communication off;  $V_{CC}$  voltage on) guarantee minimized current consumption.



**LIN Bus Transceiver with Integrated Voltage Regulator**

# **ATA6620N**





#### **Figure 1-1.** Block Diagram



# **2. Pin Configuration**

**Figure 2-1.** Pinning SO8



#### **Table 2-1.** Pin Description



#### **2 ATA6620N**

# **3. Functional Description**

### **3.1 Physical Layer Compatibility**

Since the LIN physical layer is independent from higher LIN layers (e.g., the LIN protocol layer), all nodes with a LIN physical layer according to revision 2.0 can be mixed with LIN physical layer nodes, which, according to older versions (i.e., LIN 1.0, LIN 1.1, LIN 1.2, LIN 1.3), are without any restrictions.

### **3.2 Supply Pin (VS)**

LIN operating voltage is V<sub>S</sub> = 5V to 18V. After switching on V<sub>S</sub>, the IC starts with the Pre-normal mode and the voltage regulator is switched on (that is, 5V/50 mA output capability).

The supply current in Sleep mode is typically 10  $\mu$ A and 40  $\mu$ A in Silent mode.

### **3.3 Ground Pin (GND)**

The IC is neutral on the LIN pin in case of GND disconnection. It is able to handle a ground shift up to 3V for supply voltage above 9V at the VS pin.

### **3.4 Voltage Regulator Output Pin (VCC)**

The internal 5V voltage regulator is capable of driving loads with up to 50 mA, supplying the microcontroller and other ICs on the PCB. It is protected against overload by means of current limitation and overtemperature shut-down. Furthermore, the output voltage is monitored and will cause a reset signal at the NRES output pin if it drops below a defined threshold  $V_{\text{thun}}$ .

### **3.5 Undervoltage Reset Output (NRES)**

This push-pull output is supplied from the  $V_{CC}$  voltage. If the  $V_{CC}$  voltage falls below the undervoltage detection threshold of  $V_{t_{\text{hun}}}$ , NRES switches to low after tres\_f (see [Figure 4-7 on page](#page-10-0) [11\)](#page-10-0) except the IC is switched into Sleep mode. Even if  $V_{CC} = 0V$  the NRES stays low, because it is internally driven from the V<sub>S</sub> voltage. If V<sub>S</sub> voltage ramps down, NRES stays low until  $V<sub>S</sub>$  < 1.5V and then becomes highly resistive.

The implemented undervoltage delay keeps NRES low for  $t_{\text{Reset}} = 10$  ms after  $V_{\text{CC}}$  reaches its nominal value.

### **3.6 Bus Pin (LIN)**

A low-side driver with internal current limitation and thermal shutdown, as well as an internal pull-up resistor according to LIN specification 2.0 is implemented. The voltage range is from –40V to +60V. This pin exhibits no reverse current from the LIN bus to V<sub>S</sub>, even in the case of a GND shift or  $V_{\text{Batt}}$  disconnection. The LIN receiver thresholds are compatible with the LIN protocol specification.

The fall time (from recessive to dominant) and the rise time (from dominant to recessive) are slope controlled. The output has a short-circuit limitation. This is a self-adapting current limitation; that is, during current limitation, as the chip temperature increases, the current decreases.





### **3.7 Input/Output Pin (TXD)**

This pin is the microcontroller interface to control the state of the LIN output. TXD must be pulled to ground in order to drive the LIN bus low. If TXD is high or unconnected (internal pull-up resistor), the LIN output transistor is turned off and the bus is in the recessive state.

## **3.8 Dominant Time-out Function (TXD)**

The TXD input has an internal pull-up resistor. An internal timer prevents the bus line from being driven permanently in the dominant state. If TXD is forced to low longer than  $t_{DOM} > 4$  ms, the LIN bus driver is switched to the recessive state. To reset this dominant time-out mode, TXD must be switched to high (> 10 µs) before normal data transmission can be started.

### **3.9 Output Pin (RXD)**

This pin reports the state of the LIN bus to the microcontroller. LIN high (recessive state) is reported by a high level at RXD; LIN low (dominant state) is reported by a low level at RXD. The output has an internal pull-up structure with typically 5 kΩ to  $V_{CC}$ . The AC characteristics are measured with an external load capacitor of 20 pF.

The output is short-circuit protected. In unpowered mode (that is,  $\mathsf{V}_\mathsf{S} = \mathsf{O}\mathsf{V}$ ), RXD is switched off.

### **3.10 Enable Input Pin (EN)**

This pin controls the operation mode of the interface. After power up of  $\mathsf{V}_{\mathsf{S}}$  (battery), the IC switches to Pre-normal mode, even if EN is low or unconnected (internal pull-down resistor). If EN is high, the interface is in Normal mode.

A falling edge at EN while TXD is still high forces the device to Silent mode. A falling edge at EN while TXD is low forces the device to Sleep mode.

# **4. Mode of Operation**





#### **Table 4-1.** Mode of Operation



### **4.1 Normal Mode**

This is the normal transmitting and receiving mode of the LIN Interface, in accordance with LIN specification 2.0. The  $V_{CC}$  voltage regulator operates with a 5V output voltage, with a low tolerance of ±2% and a maximum output current of 50 mA.

If an undervoltage condition occurs, NRES is switched to low and the ATA6620N changes state to Pre-normal mode. All features are available.





### **4.2 Modes of Reduced Current Consumption**

#### **4.2.1 Silent Mode**

A falling edge at EN while TXD is high switches the IC into Silent mode. The TXD Signal has to be logic high during the Mode Select window (see [Figure 4-2 on page 6\)](#page-5-0). For EN and TXD either two independent outputs can be used, or two outputs from the same microcontroller port; in the second case, the mode change is only one command.

In Silent mode the transmission path is disabled. Supply current from  $V_{\text{Batt}}$  is typically  $I_{VSSi}$  = 40 µA with no load at the  $V_{CC}$  regulator.

The overall supply current from  $V_{\text{Batt}}$  is the result of 40 µA plus the  $V_{\text{CC}}$  regulator output current  $I_{VCCs}$ 

The 5V regulator is in low tolerance mode (4.65V to 5.35V) and can source up to 50 mA. In Silent mode the internal slave termination between pin LIN and pin VS is disabled to minimize the power dissipation in case pin LIN is short-circuited to GND. Only a weak pull-up current (typically 10 µA) between pin LIN and pin VS is present.

The Silent mode voltage is sufficient to run an external microcontroller on the ECU, for example in Power Down mode. The undervoltage reset is  $V_{\text{CChs}} < 4.4V$ . If an undervoltage condition occurs, NRES is switched to low and the ATA6620N changes state to Pre-normal mode.

A falling edge at pin LIN followed by a dominant bus level maintained for a certain time period  $(t<sub>bus</sub>)$  results in a remote wake-up request. The device switches from Silent mode to Pre-normal mode, then the internal LIN slave termination resistor is switched on. The remote wake-up request is indicated by a low level at pin RXD to interrupt the microcontroller and a high level at pin TXD (see [Figure 4-3 on page 7](#page-6-0)).

With EN high, ATA6620N switches directly from Silent- via Pre-normal to Normal mode.



<span id="page-5-0"></span>**Figure 4-2.** Switch to Silent Mode

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<span id="page-6-0"></span>**Figure 4-3.** LIN Wake-up Waveform Diagram from Silent Mode





#### **4.2.2 Sleep Mode**

A falling edge at EN while TXD is low switches the IC into Sleep mode. The TXD Signal has to be logic low during the Mode Select window (see [Figure 4-4\)](#page-7-0). We recommend using the same microcontroller port for EN as for TXD; in this case the mode change is only one command.

In Sleep mode the transmission path is disabled. Supply current from  $V_{\text{Batt}}$  is typically  $I_{VSsleep}$  = 10 µA. The  $V_{CC}$  regulator is switched off; NRES and RXD are low. The internal slave termination between pin LIN and pin VS is disabled to minimize the power dissipation in case pin LIN is short-circuited to GND. Only a weak pull-up current (typically 10 µA) between pin LIN and pin VS is present.

A falling edge at pin LIN followed by a dominant bus level maintained for a certain time period  $(t_{bus})$  results in a remote wake-up request. The device switches from Sleep mode to Pre-normal mode. The  $V_{CC}$  regulator is activated and the internal LIN slave termination resistor is switched on. The remote wake-up request is indicated by a low level at pin RXD to interrupt the microcontroller and a high level at pin TXD (see [Figure 4-5 on page 9](#page-8-0)).

With EN high you can switch directly from Silent to Normal mode. In the application where the ATA6620N supplies the microcontroller, the wake-up from Sleep mode is only possible via pin LIN.

If the device is switched into Sleep mode,  $V_{CC}$  ramps down without generating an undervoltage reset at pin NRES.



#### <span id="page-7-0"></span>**Figure 4-4.** Switch to Sleep Mode

<span id="page-8-0"></span>



#### **4.2.3 Wake Up from Sleep/Silent Mode at an Insufficient Falling Edge at Pin LIN**

If the ATA6620N is in Sleep mode or Silent mode and the voltage at the LIN Bus falls to a value lower than VLINL <  $V_s - 3.3V$  (see ["Electrical Characteristics"](#page-13-0) numbers 9.5 and 9.6) but higher than 0.6  $\times$  V<sub>S</sub>, then a wake up is detected and the circuit switches to pre-normal mode and the internal NMOS- transistor connected to the pin TXD is switched on and pulls down the pin TXD to Ground. The following figure shows the corresponding diagram for the wake-up from silent mode. The wake-up process from Sleep mode works analogue to this.









When designing the complete system it has to be considered, that in this case (only in pre-normal mode) the pin TXD of the ATA6620N works as an output.

#### **4.3 Pre-normal Mode**

At system power-up the device automatically switches to Pre-normal mode. The voltage regulator is switched on ( $V_{CC}$  = 5V/50 mA) (see [Figure 4-7 on page 11\)](#page-10-0) after typically  $t_{VCC}$  > 300 µs. The NRES output switches to low for  $t_{res} = 10$  ms and sends a reset to the microcontroller. LIN communication is switched off, and the undervoltage detection is active.

A power-down of  $V_{\text{Batt}}$  (V<sub>S</sub> < 4.15V) during Silent or Sleep mode switches into Pre-normal mode after powering up the IC. During this mode the TXD pin is an output.

### **4.4 Unpowered Mode**

If battery voltage is connected to the application circuit (see [Figure 4-7\)](#page-10-0), the voltage at the VS pin increases due to the block capacitor. When V<sub>S</sub> is higher than the V<sub>S</sub> undervoltage threshold,  $V_{\text{Sth}}$ , the IC-mode changes from Unpowered to Pre-normal mode. The  $V_{\text{CC}}$  output voltage reaches nominal value after t<sub>VCC</sub>. This time depends on the V<sub>CC</sub> capacitor and the load.

NRES is low for the reset time delay  $t_{\text{Reset}}$ ; no mode change is possible during this time.

<span id="page-10-0"></span>



# **5. Fail-safe Features**

- During a short circuit at LIN, the output limits the output current to I<sub>BUSLIM</sub>. Due to the power dissipation, the chip temperature exceeds  $t_{LINoff}$  and the LIN output is switched off. The chip cools down and after a hysteresis of  $t_{\text{hys}}$ , switches the output on again. During LIN overtemperature switch-off, the  $V_{CC}$  regulator works independently.
- There are now reverse currents < 3  $\mu$ A at pin LIN during loss of V<sub>Batt</sub> or GND. This is optimal behavior for bus systems where some slave nodes are supplied from battery or ignition.
- During a short circuit at VCC, the output limits the output current to  $I_{VCCn}$ . Because of undervoltage, NRES switches to low and sends a reset to the microcontroller. The IC switches into Pre–normal mode. If the chip temperature exceeds the value t<sub>VCCoff</sub>, the V<sub>CC</sub> output switches off. The chip cools down and after a hysteresis of  $t_{\text{hvs}}$ , switches the output on again. Because of Pre-normal mode, the  $V_{CC}$  voltage will switch on again although EN is switched off from the microcontroller.The microcontroller can then start with normal operation.
- Pin EN provides a pull-down resistor to force the transceiver into recessive mode if EN is disconnected.
- Pin RXD is set floating if  $V_{\text{Batt}}$  is disconnected.
- Pin TXD provides a pull-up resistor to force the transceiver into recessive mode if TXD is disconnected.





# **6. Voltage Regulator**

The voltage regulator needs an external capacitor for compensation and to smooth the disturbances from the microcontroller. It is recommend to use an tantalum capacitor with  $C > 10 \mu F$ and a ceramic capacitor with  $C = 100$  nF. The values of these capacitors can be varied by the customer, depending on the application.

During mode change from Silent to Normal mode, the voltage regulator ramps up to 6V for only a few microseconds before it drops back to 5V. This behavior depends on the value of the load capacitor. With 4.7 µF, the overshoot voltage has its greatest value. This voltage decreases with higher or lower load capacitors.

With this special SO8 package (fused lead frame to pin3) an  $R<sub>thia</sub>$  of 80 K/W is achieved.

Therefore it is recommended to connect pin 3 with a wide GND plate on the printed board to get a good heat sink.

The main power dissipation of the IC is created from the  $V_{CC}$  output current  $I_{VCC}$ , which is needed for the application.

[Figure 6-1](#page-11-0) shows the safe operating area of the ATA6620N.

<span id="page-11-0"></span>**Figure 6-1.** Save Operating Area versus V<sub>CC</sub> Output Current and Supply Voltage V<sub>S</sub> at Different Ambient Temperatures with  $R<sub>thia</sub> = 80$  K/W



For programming purposes of the microcontroller it is potentially necessary to supply the VCC output via an external power supply while the VS pin of the system basis chip is disconnected. This behavior is no problem for the system basis chip.

# **7. Absolute Maximum Ratings**

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.







# <span id="page-13-0"></span>**8. Electrical Characteristics**

5V < V $_{\rm S}$  < 18V, T $_{\rm amb}$  = –40°C to 125°C



\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

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# **8. Electrical Characteristics (Continued)**





\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter





# **8. Electrical Characteristics (Continued)**

5V < V $_{\rm S}$  < 18V, T $_{\rm amb}$  = –40°C to 125°C



\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter

# **8. Electrical Characteristics (Continued)**





\*) Type means: A = 100% tested, B = 100% correlation tested, C = Characterized on samples, D = Design parameter





<span id="page-17-0"></span>



#### **Figure 8-2.** Application Circuit







# **9. Ordering Information**



# **10. Package Information**

Package: SO 8

Dimensions in mm









specifications according to DIN technical drawings

Issue: 1; 15.08.06 Drawing-No.: 6.541-5031.01-4

# **11. Revision History**

Please note that the following page numbers referred to in this section refer to the specific revision mentioned, not to this document.







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